



A unified approach to quasiparticle interference in two-dimensional materials

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Graphene 2018, Dresden 06/2018

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Scanning tunneling spectroscopy













PRL 118, 116401 (2017)

Fourier transform STS (FT-STS)

$$\rho(\mathbf{q} + \mathbf{G}, \varepsilon) = \int d\mathbf{r} \, e^{-i(\mathbf{q} + \mathbf{G}) \cdot \mathbf{r}} \rho(\mathbf{r}, \varepsilon)$$



FIG. 1. Scattering patterns in strongly doped graphene. (a) Inverted LEED pattern of gr/Cs/Ir(111) at E = 143.5 eV, the intercalated Cs forms a $(2 \times 2)_{or}$ superstructure. The sketch **PRL 118, 116401 (2017)**



- Scattering (elastic) on constant energy contours in k-space.
- Nesting vectors (backscattering) dominate \rightarrow Friedel osc.
- Replicas outside 1'st BZ (Bragg).
- JDOS: $\rho_{\rm JDOS}(\mathbf{q},\varepsilon) \propto \sum_{\mathbf{k}} \rho_{\mathbf{k}}(\varepsilon) \rho_{\mathbf{k}+\mathbf{q}}(\varepsilon)$

A "unified" FT-STS theory



LDOS:
$$\rho(\mathbf{r}, \varepsilon) = -1/\pi \text{Im}G(\mathbf{r}, \mathbf{r}; \varepsilon)$$

FT of LDOS:

$$\rho(\mathbf{q} + \mathbf{G}, \varepsilon) = -\frac{1}{2\pi i} \sum_{mn} \sum_{\mathbf{k}} n_{\mathbf{k}, \mathbf{q}}^{mn}(\mathbf{G}) \times \left[G_{\mathbf{k} + \mathbf{q}, \mathbf{k}}^{nm}(\varepsilon) - G_{\mathbf{k}, \mathbf{k} + \mathbf{q}}^{mn}(\varepsilon)^* \right]$$

Interference in q space

Scattering processes

$$n_{\mathbf{k},\mathbf{q}}^{mn}(\mathbf{G}) = \langle \psi_{m\mathbf{k}} | e^{-i(\mathbf{q}+\mathbf{G})\cdot\hat{\mathbf{r}}} | \psi_{n\mathbf{k}+q} \rangle$$
(pristine)

$$V_{\mathbf{k}\mathbf{k}'}^{mn} = \langle \psi_{m\mathbf{k}} | \hat{V} | \psi_{n\mathbf{k}+q} \rangle$$
(defect/impurity)



- Supercell
- LCAO basis
- Spin-orbit
- *T*-matrix
- NxN BZ sampling



Kaasbjerg *et al.*, PRB **96**, 241411(R) (2017)

Graphene tight-binding

$$H_0 = -t \sum_{\mathbf{k}} [\phi_{\mathbf{k}} c^{\dagger}_{A\mathbf{k}} c_{B\mathbf{k}} + \text{h.c.}]$$
$$\phi_{\mathbf{k}} = 1 + e^{i\mathbf{k}\cdot\mathbf{a_1}} + e^{i\mathbf{k}\cdot\mathbf{a_2}}$$



Impurity model:

 $\boldsymbol{V} = V_0 \begin{pmatrix} 1 & 0 \\ 0 & 0 \end{pmatrix}$



Breaks *A*, *B* sublattice symmetry $\rightarrow q=2k$ backscattering allowed



Weak impurity



 $\delta
ho({f R})$



- Filled disc instead of *q*=2*k* backscatter ring + strongly anisotropic intervalley features (PRL **100**, 076601 (2008)).
- Backscatter ring at Bragg points (weak intensity).

Role of (intrinsic) chirality

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$$\mathcal{H}_{\mathbf{k}} = \hbar v_F \mathbf{k} \cdot \boldsymbol{\sigma}$$

$$\boldsymbol{\chi}_{s\mathbf{k}} = (1, se^{i heta_{\mathbf{k}}})^T = \bigoplus$$



Phase-factor element:

$$\begin{split} n_{\mathbf{k},\mathbf{q}}^{ss'}(\mathbf{G}) &= \langle \psi_{s\mathbf{k}} | e^{-i(\mathbf{q}+\mathbf{G})\cdot\hat{\mathbf{r}}} | \psi_{s'\mathbf{k}+\mathbf{q}} \rangle & \psi_{s\mathbf{k}}(\mathbf{r}) = \frac{1}{\sqrt{A}} e^{i\mathbf{k}\cdot\mathbf{r}} \chi_{s\mathbf{k}} \\ & \rightarrow \chi_{s\mathbf{k}}^{\dagger} M(\mathbf{q}+\mathbf{G}) \chi_{s'\mathbf{k}+\mathbf{q}} \quad ; \quad M(\mathbf{q}) = \begin{pmatrix} e^{-i\mathbf{q}\cdot\mathbf{R}_{A}} & 0\\ 0 & e^{-i\mathbf{q}\cdot\mathbf{R}_{B}} \end{pmatrix} \\ & \underbrace{\text{Intravalley } (\mathbf{q}\sim\mathbf{0})} & \underbrace{\text{Intervalley } (\mathbf{q}=\mathbf{K},\mathbf{K}')}_{and Bragg } (\mathbf{G}\neq\mathbf{0}) \\ & M(\mathbf{q}) \approx \sigma_{0} & M(\mathbf{q}) \neq \sigma_{0} \\ & n_{\mathbf{k},\mathbf{q}}^{ss'} = \frac{1}{2} [1 + ss' \exp(i\theta_{\mathbf{k},\mathbf{k}+\mathbf{q}})] & n_{\mathbf{k},\mathbf{q}}^{ss'} = F(\theta_{\mathbf{k}},\theta_{\mathbf{k}+\mathbf{q}}) \end{split}$$

Role of (intrinsic) chirality



QPI/FT-STS in graphene





PRL **101,** 206802 (2008) PHYSICAL REVIEW B **86**, 045444 (2012)



PHYSICAL REVIEW B 95, 075429 (2017)

PRL 118, 116401 (2017)



100mV 50mV -50mV -150mV -350mV -450mV -550mV -650mV





Moiré minibands



Resonant impurity



Strong impurity: $V_0 = -16 \,\mathrm{eV}$

















• Reappearance of broad backscatter ring at resonance

 \rightarrow standard "scattering picture" breaks down.

Summary

- 1. QPI/FT-STS unique method for probing QP states and the scattering properties of defects \rightarrow direct fingerprint.
- 2. Unified theoretical framework for calculating FT-STS/QPI spectra in two-dimensional materials:
 - Impurity matrix element (scattering processes).
 - Phase-factor matrix element (interference).
- 3. The latter can mask scattering processes in FT-STS:
 - intravalley backscattering in graphene (spinor overlap).
- 4. Uncovered a hitherto unexplored variant of the backscatter ring for resonant scattering in graphene.
- 5. Relevant for QPI in Moiré lattices, other 2D materials (e.g., silicene), as well as surfaces of TIs and Weyl semimetals.







Acknowledgments



Antti-Pekka Jauho

DTU Nanotech





Johannes Handberg Juul Martiny DTU Nanotech



Danmarks Grundforskningsfond Danish National Research Foundation



Tony Low UMN, USA



Marie Sklodowska-Curie (COFUNDfellowsDTU)